

RF Power Field Effect Transistor

LDMOS, 800—2200 MHz, 2W, 28V

4/14/05

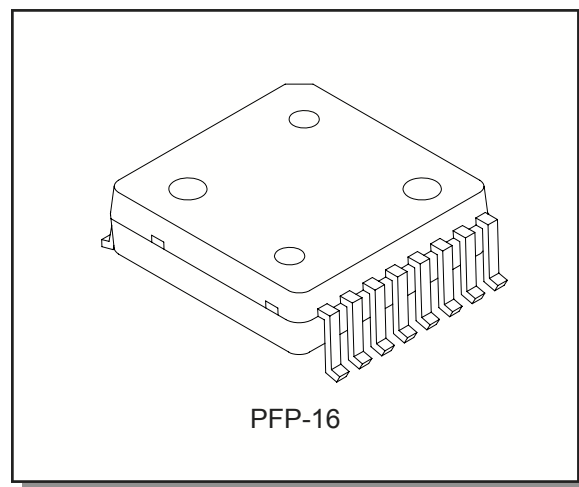
Preliminary

MAPLST0822-002PP

Features

- Designed for broadband commercial applications up to 2.2GHz
- High Gain, High Efficiency and High Linearity
- Ease of Design for Gain and Insertion Phase Flatness
- Excellent Thermal Stability
- W-CDMA Performance at 2.17GHz, 28Vdc
 - Average Output Power: 28dBm @ -39dBc ACPR
 - Gain: 14.5dB (typ.)
 - Efficiency: 23% (typ.)
 - 10:1 VSWR Ruggedness at 2W (CW), 28V, 2.11GHz
- Performance at 960MHz, 26Vdc, P_{1dB}
 - Average Output Power: 2W min.
 - Gain: 20dB (typ.)
 - Efficiency: 50% (typ.)
 - 10:1 VSWR Ruggedness at 2W, 26V, 960MHz

Package Style



Maximum Ratings

Parameter	Symbol	Rating	Units
Drain—Source Voltage	V_{DS}	65	V _{dc}
Gate—Source Voltage	V_{GS}	+15, -0.5	V _{dc}
Total Power Dissipation @ $T_C = 25\text{ }^{\circ}\text{C}$	P_D	6.9	W
Storage Temperature	T_{STG}	-65 to +150	$^{\circ}\text{C}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	18	$^{\circ}\text{C/W}$

NOTE—CAUTION—MOS devices are susceptible to damage from electrostatic charge. Precautions in handling and packaging MOS devices should be observed.

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Characteristic	Symbol	Min	Typ	Max	Unit
DC CHARACTERISTICS @ 25°C					
Drain-Source Breakdown Voltage ($V_{GS} = 0 \text{ Vdc}$, $I_D = 30 \text{ } \mu\text{Adc}$)	$V_{(BR)DSS}$	65	—	—	Vdc
Gate Threshold Voltage ($V_{ds} = 26 \text{ Vdc}$, $I_d = 25 \text{ mA}$)	$V_{GS(th)}$	2	—	5	Vdc
Gate Quiescent Voltage ($V_{ds} = 26 \text{ Vdc}$, $I_d = 25 \text{ mA}$)	$V_{GS(Q)}$	3	—	5	Vdc
Drain-Source On-Voltage ($V_{gs} = 10 \text{ Vdc}$, $I_d = 0.1 \text{ A}$)	$V_{DS(on)}$	—	0.30	—	Vdc

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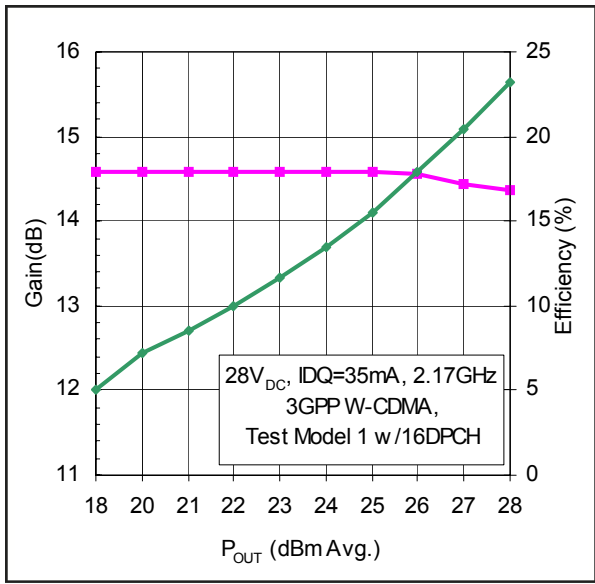
Characteristic	Symbol	Min	Typ	Max	Unit
RF FUNCTIONAL TESTS @ 25°C (In M/A-COM Test Fixture)					
Common Source Amplifier Gain ($V_{DD} = 28 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 2170 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	G_P	—	14	—	dB
Drain Efficiency ($V_{DD} = 28 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 2170 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	$EFF (\eta)$	—	38	—	%
Input Return Loss ($V_{DD} = 28 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 2170 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	IRL	—	-9	—	dB
Output VSWR Tolerance ($V_{DD} = 28 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 2170 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$, VSWR = 10:1, All Phase Angles at Frequency of Tests)	Ψ	No Degradation In Output Power Before and After Test			

RF FUNCTIONAL TESTS @ 25°C (In M/A-COM Test Fixture shown in Figure 10)					
Common Source Amplifier Gain ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1900 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	G_P	—	14.5	—	dB
Drain Efficiency ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1900 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	$EFF (\eta)$	—	40	—	%
Input Return Loss ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1900 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	IRL	—	-10	—	dB
Output VSWR Tolerance ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1900 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$, VSWR = 10:1, All Phase Angles at Frequency of Tests)	Ψ	No Degradation In Output Power Before and After Test			

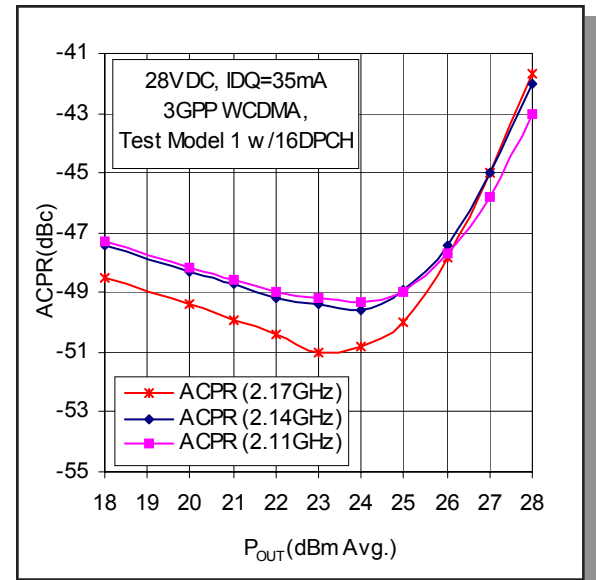
RF FUNCTIONAL TESTS @ 25°C (In M/A-COM Test Fixture)					
Common Source Amplifier Gain ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1670 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	G_P	—	15	—	dB
Drain Efficiency ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1670 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	$EFF (\eta)$	—	45	—	%
Input Return Loss ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1670 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	IRL	—	-11	—	dB
Output VSWR Tolerance ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 35 \text{ mA}$, $f = 1670 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$, VSWR = 10:1, All Phase Angles at Frequency of Tests)	Ψ	No Degradation In Output Power Before and After Test			

RF FUNCTIONAL TESTS @ 25°C (In M/A-COM Test Fixture shown in Figure 12)					
Common Source Amplifier Gain ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 50 \text{ mA}$, $f = 960 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	G_P	—	20	—	dB
Drain Efficiency ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 50 \text{ mA}$, $f = 960 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	$EFF (\eta)$	—	50	—	%
Input Return Loss ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 50 \text{ mA}$, $f = 960 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$)	IRL	—	-12	—	dB
Output VSWR Tolerance ($V_{DD} = 26 \text{ Vdc}$, $I_{DQ} = 50 \text{ mA}$, $f = 960 \text{ MHz}$, $P_{OUT} = 2 \text{ W}$, VSWR = 10:1, All Phase Angles at Frequency of Tests)	Ψ	No Degradation In Output Power Before and After Test			

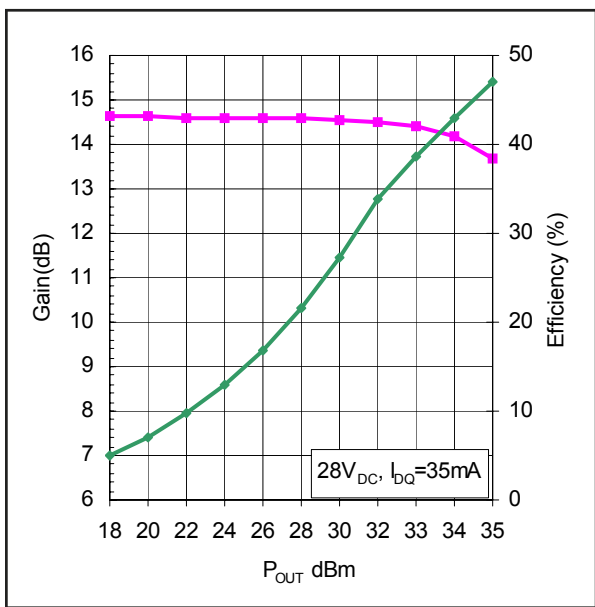
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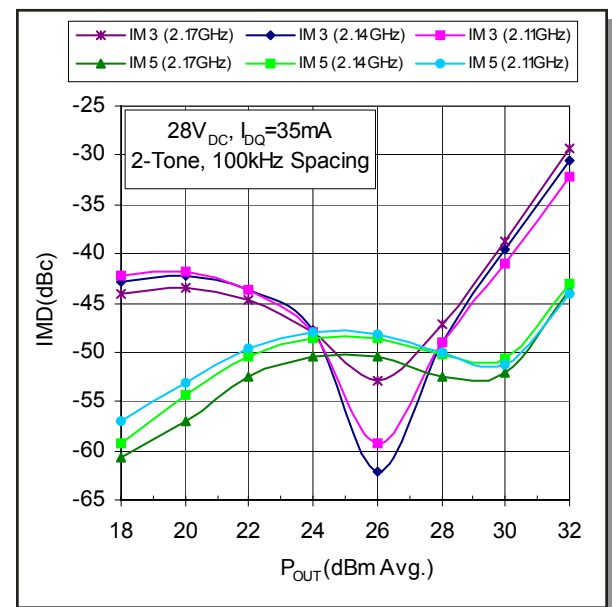
Graph 1. W-CDMA: Gain and Efficiency versus Output Power



Graph 2. W-CDMA: ACPR versus Output Power

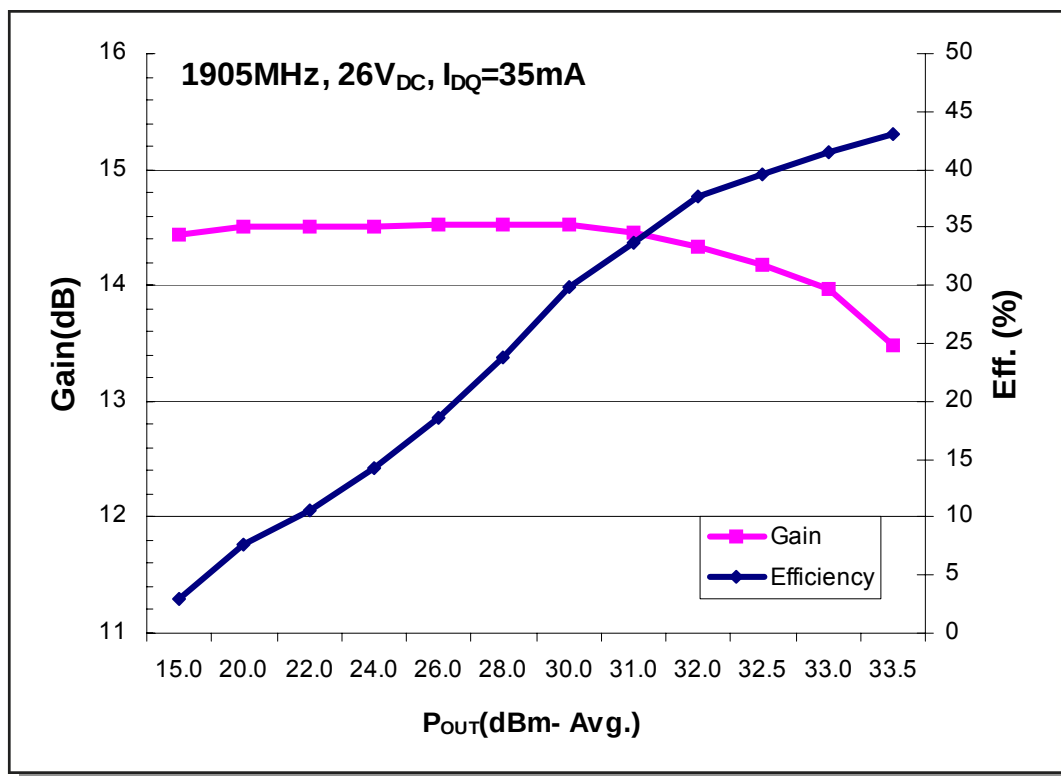


Graph 3. CW: Gain and Efficiency versus Output Power

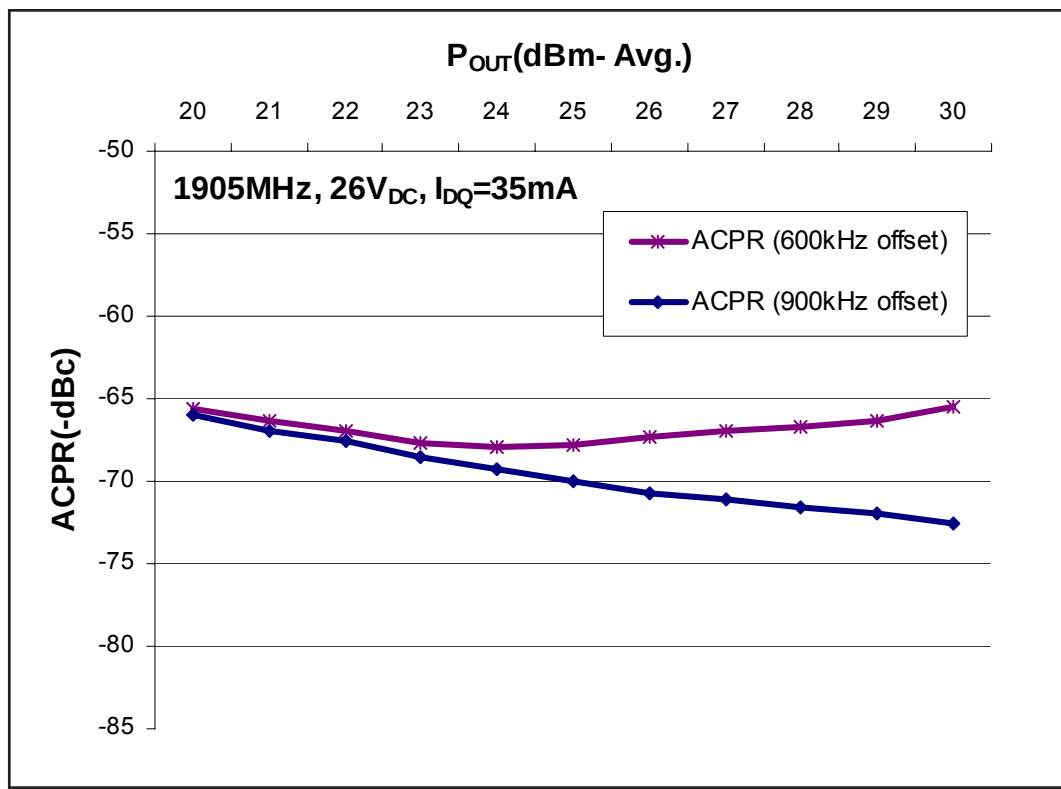


Graph 4. Two Tone: Intermodulation Distortion versus Output Power

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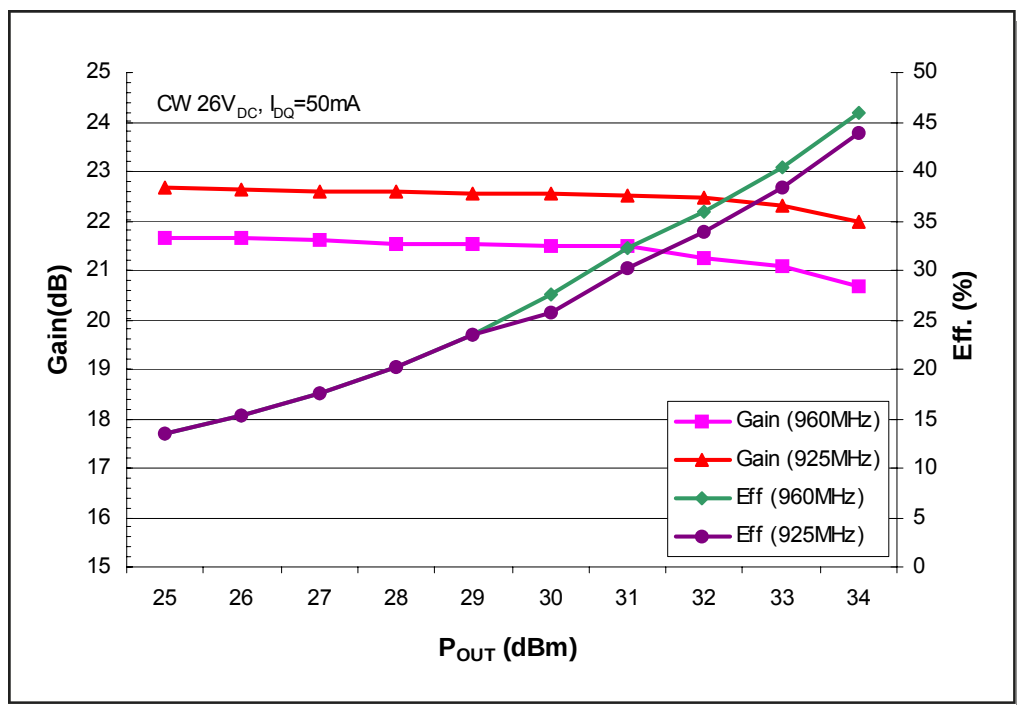


Graph 5. PHS Power Gain and Drain Efficiency vs. Output Power

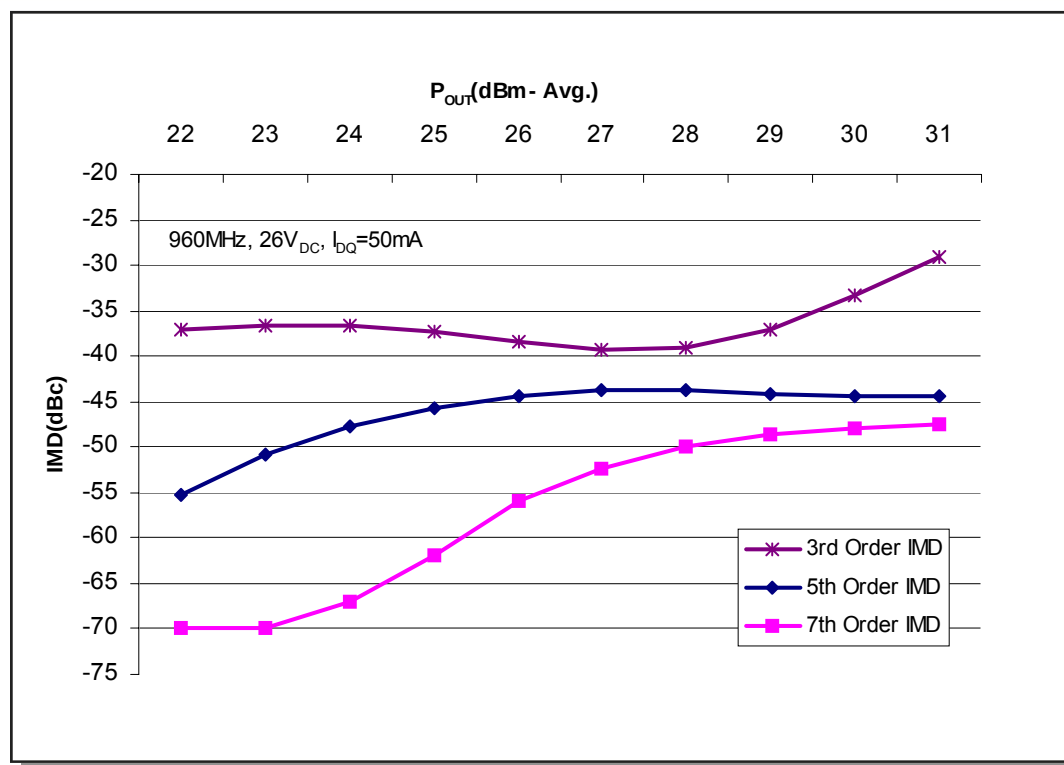


Graph 6. PHS ACPR vs. Output Power

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Graph 7. Power Gain and Drain Efficiency vs. Output Power



Graph 8. Intermodulation Distortion vs. Output Power

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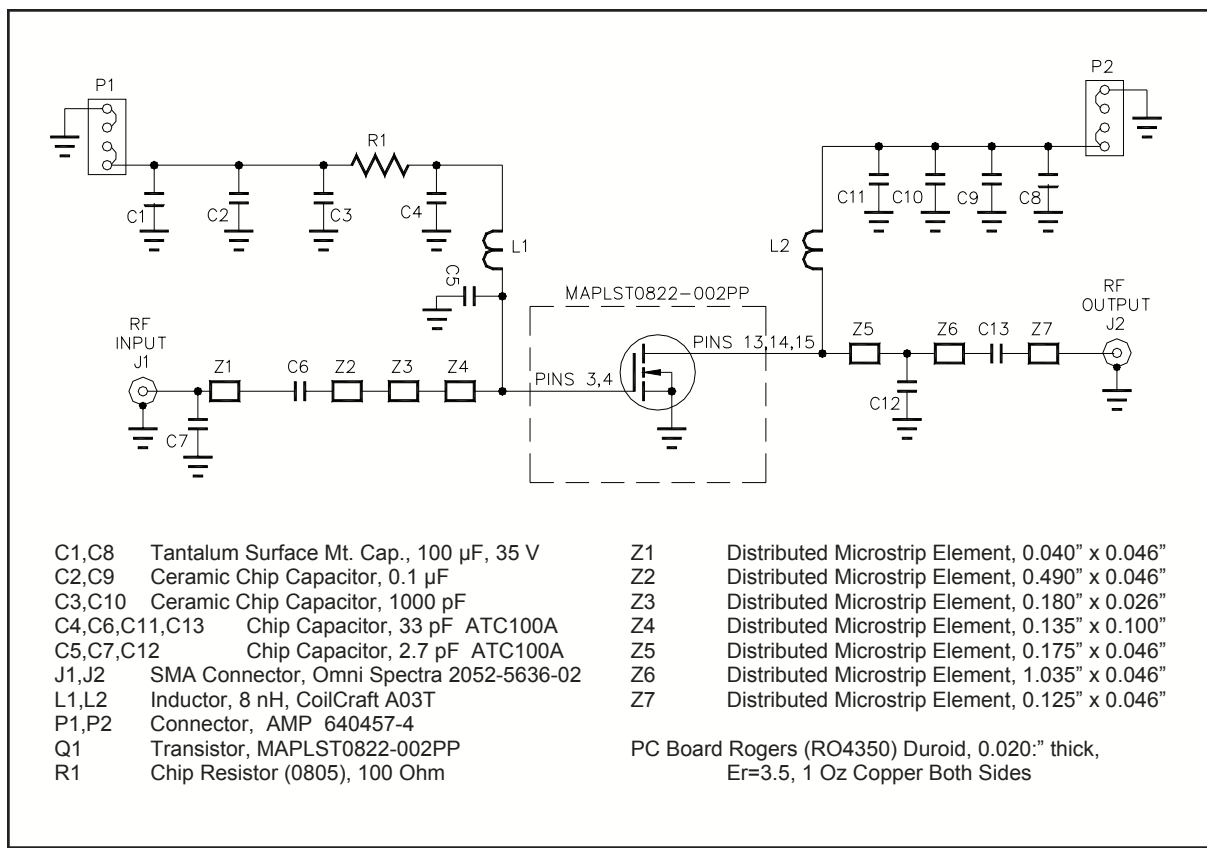


Figure 9. 1880—1920 MHz Test Fixture Schematic

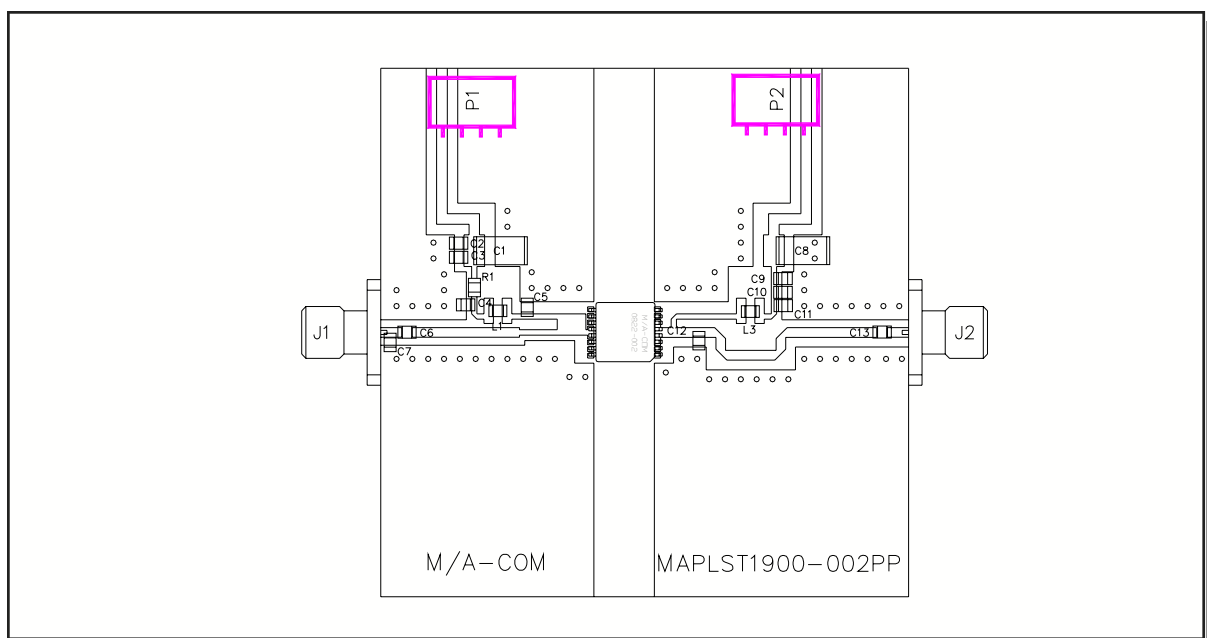


Figure 10. 1880—1920 MHz Test Fixture Component Layout

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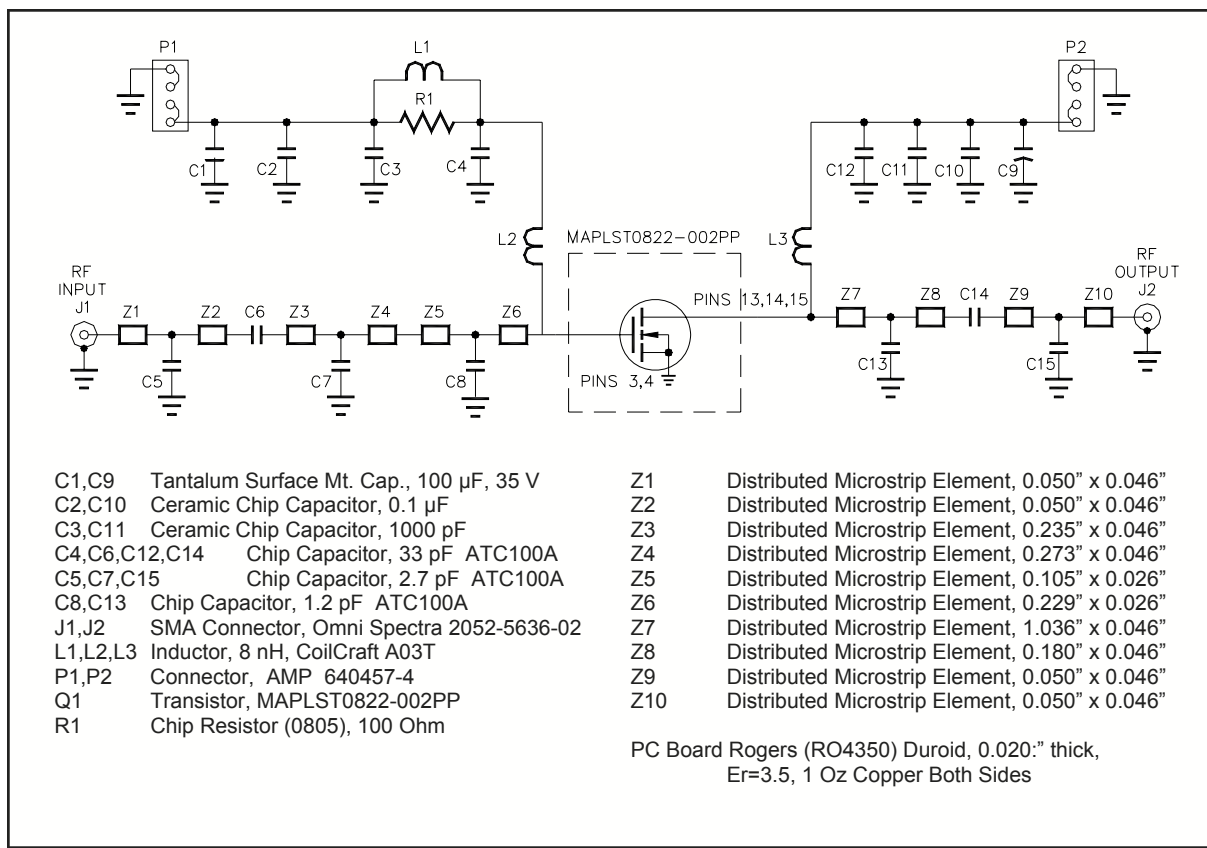


Figure 11. 920–960 MHz Test Fixture Schematic

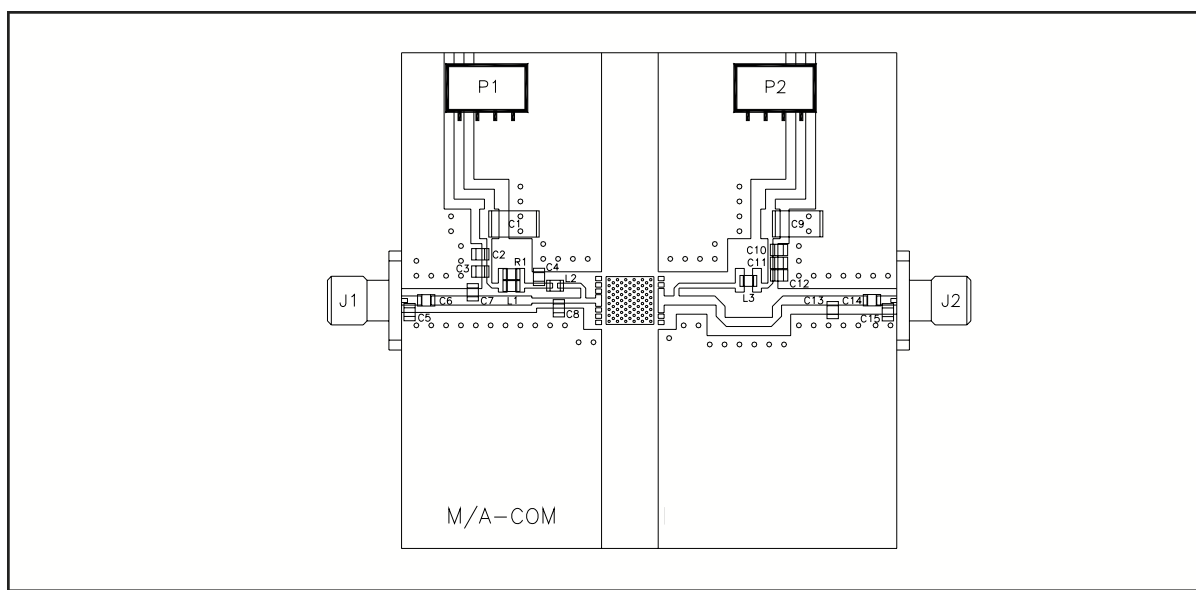
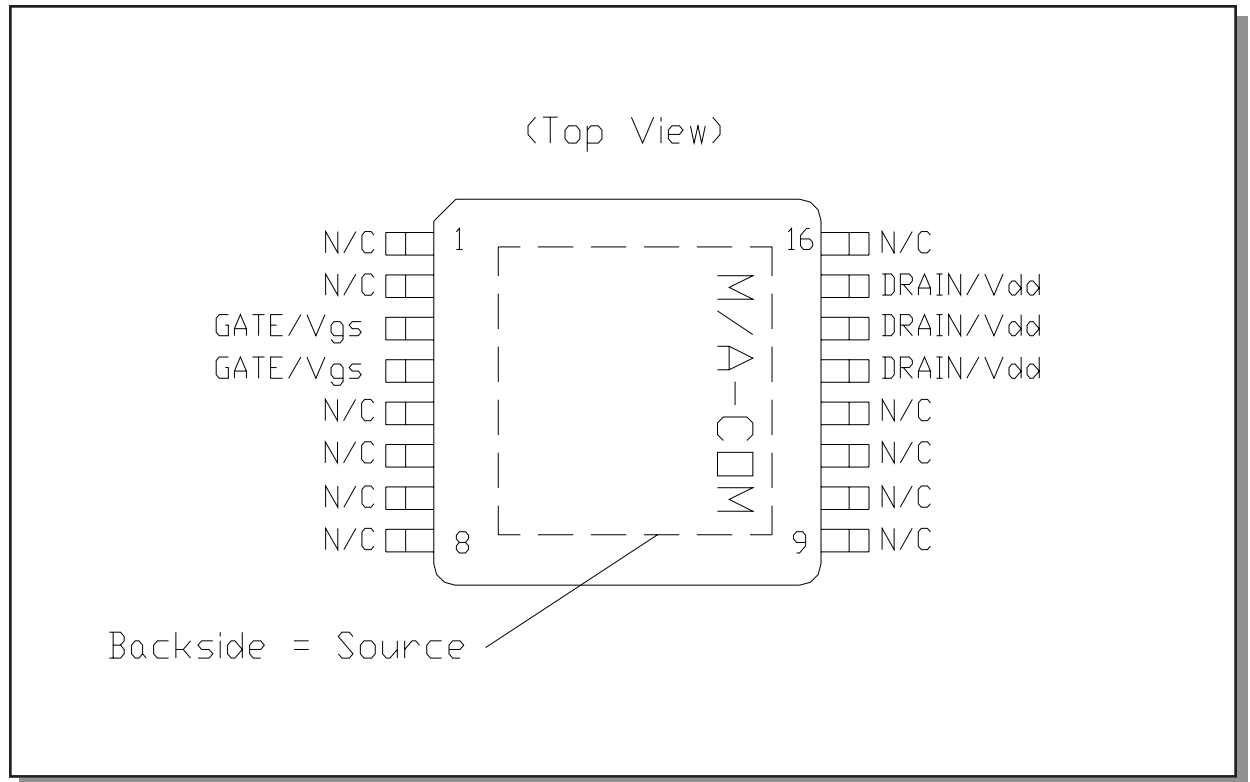
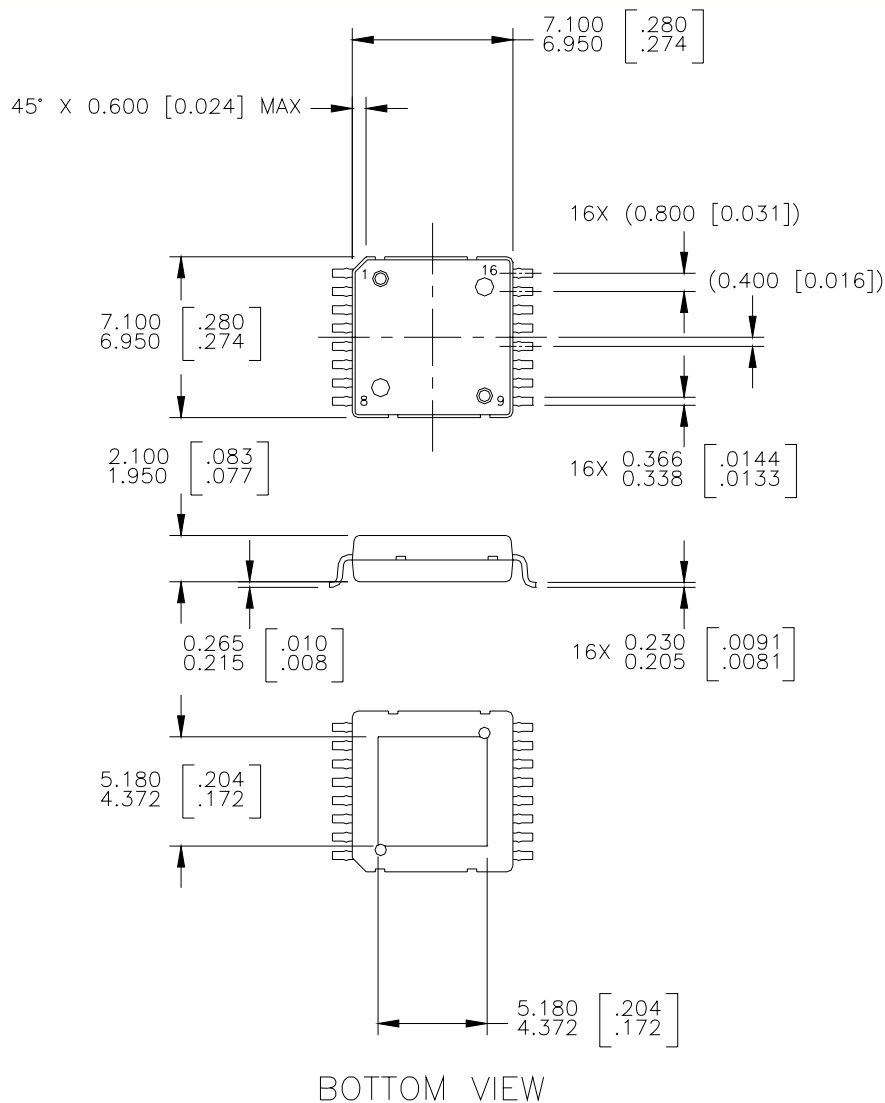


Figure 12. 920–960 MHz Test Fixture Component Layout

**Figure 13. PFP-16 Pin Connections**

Package Dimensions



DIMENSIONS ARE IN MILLIMETERS AND [INCHES]

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